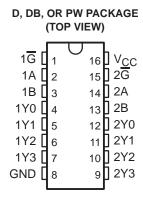
### SN74LVC139A DUAL 2-LINE TO 4-LINE DECODER/DEMULTIPLEXER

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- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) Submicron Process
- Inputs Accept Voltages to 5.5 V
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   < 0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
   2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages



### description

This dual 2-line to 4-line decoder/demultiplexer is designed for 1.65-V to 3.6-V  $V_{CC}$  operation.

The device comprises two individual 2-line to 4-line decoders in a single package. The active-low enable  $(\overline{G})$  input can be used as a data line in demultiplexing applications. These decoders/demultiplexers feature fully buffered inputs, each of which represents only one normalized load to its driving circuit.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

The SN74LVC139A is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each decoder/demultiplexer)

INPUTS							
SELECT		OUTPUTS					
G	В	Α	Y3	Y2	Y1	Y0	
L	L	L	Н	Н	Н	L	
L	L	Н	Н	Н	L	Н	
L	Н	L	Н	L	Н	Н	
L	Н	Н	L	Н	Н	Н	
Н	Х	Χ	Н	Н	Н	Н	

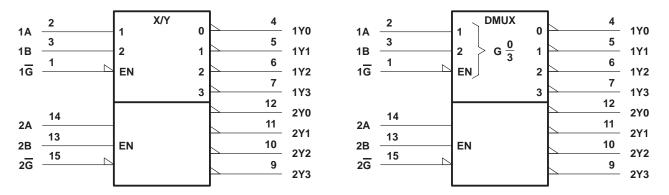


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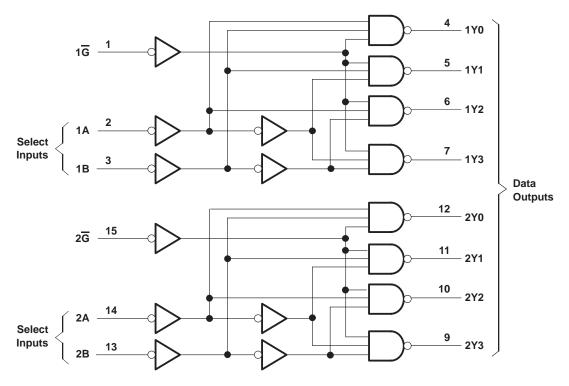


### logic symbols (alternatives)†



<sup>&</sup>lt;sup>†</sup> These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)



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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>		−0.5 V to 6.5 V
Input voltage range, V <sub>I</sub> (see Note 1)		−0.5 V to 6.5 V
Output voltage range, VO (see Notes 1 and 2)	0.5 \	$/ \text{ to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{IK}$ ( $V_I < 0$ )		–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)		–50 mA
Continuous output current, I <sub>O</sub>		±50 mA
Continuous current through V <sub>CC</sub> or GND		±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3):		
, <b>3</b> , 1	DB package	
	PW package	149°C/W
Storage temperature range, T <sub>stg</sub>		–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
- 3. The package thermal impedance is calculated in accordance with JESD 51.

#### recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
V	Supply voltage Operating Data retention on		1.65	3.6	V	
VCC			1.5		V	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V <sub>CC</sub>			
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		0.35 × V <sub>CC</sub>		
$V_{IL}$	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		
VI	Input voltage		0	5.5	V	
VO	Output voltage		0	Vcc	V	
		V <sub>CC</sub> = 1.65 V		-4	mA	
la	High-level output current	V <sub>CC</sub> = 2.3 V		-8		
ЮН		$V_{CC} = 2.7 \text{ V}$		-12		
		V <sub>CC</sub> = 3 V		-24		
		V <sub>CC</sub> = 1.65 V		4		
loi	Law L	V <sub>CC</sub> = 2.3 V		8		
IOL	Low-level output current	$V_{CC} = 2.7 \text{ V}$		12	mA	
	V <sub>CC</sub> = 3 V			24		
Δt/Δν	Input transition rise or fall rate		0	10	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP <sup>†</sup>	MAX	UNIT
	I <sub>OH</sub> = -100 μA	1.65 V to 3.6 V	V <sub>CC</sub> -0.2			
	I <sub>OH</sub> = -4 mA	1.65 V	1.2			
\/a	I <sub>OH</sub> = -8 mA	2.3 V	1.7			٧
VOH	12 mA	2.7 V	2.2			
	I <sub>OH</sub> = -12 mA	3 V	2.4			
	I <sub>OH</sub> = -24 mA	3 V	2.2			
	I <sub>OL</sub> = 100 μA	1.65 V to 3.6 V			0.2	
	I <sub>OL</sub> = 4 mA	1.65 V			0.45	
VoL	I <sub>OL</sub> = 8 mA	2.3 V			0.7	V
	I <sub>OL</sub> = 12 mA	2.7 V			0.4	
	I <sub>OL</sub> = 24 mA	3 V			0.55	
lį	V <sub>I</sub> = 5.5 V or GND	3.6 V			±5	μΑ
lcc	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			10	μΑ
ΔlCC	One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND	2.7 V to 3.6 V			500	μΑ
Ci	$V_I = V_{CC}$ or GND	3.3 V		5		pF

<sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

PARAMETER	FROM TO (UNPUT)		V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT	
	(INPOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX				
<sup>t</sup> pd	A or B	V	15.3	1	9.3		7.3	1	6.2	no			
	G	ī	13.2	1	7.2		5.2	1	4.7	ns			
t <sub>sk(o)</sub> ‡									1	ns			

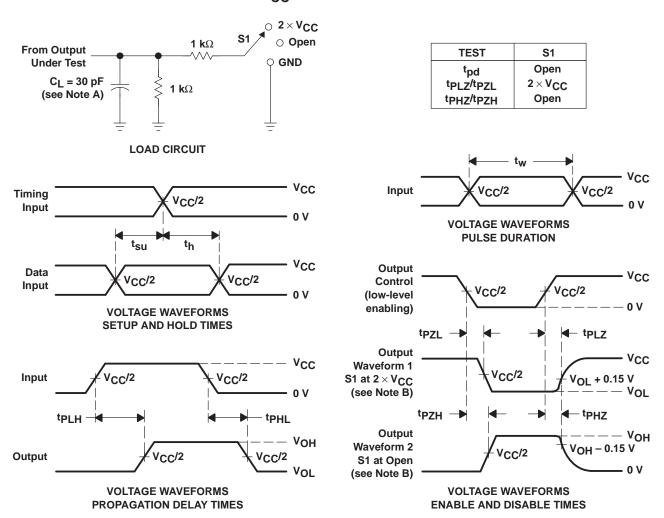
<sup>‡</sup> Skew between any two outputs of the same package switching in the same direction

### operating characteristics, T<sub>A</sub> = 25°C

PARAMETER		TEST	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	UNIT
		CONDITIONS	TYP	TYP	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz	28.5	29.5	30.5	pF



## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$

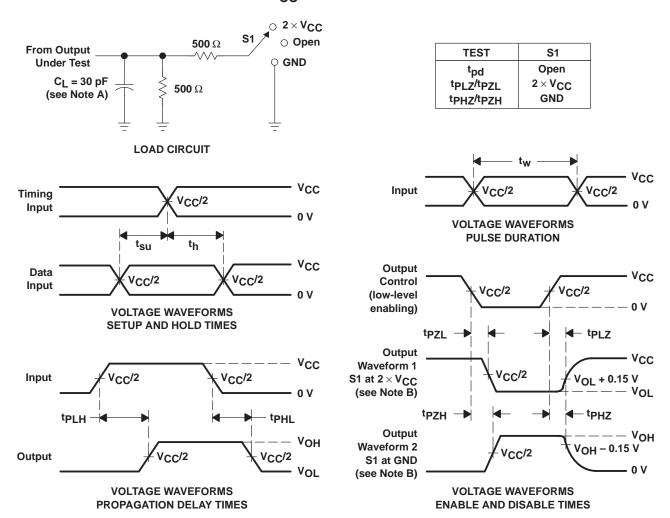


NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 2$  ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tplH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

## PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.5 V $\pm$ 0.2 V



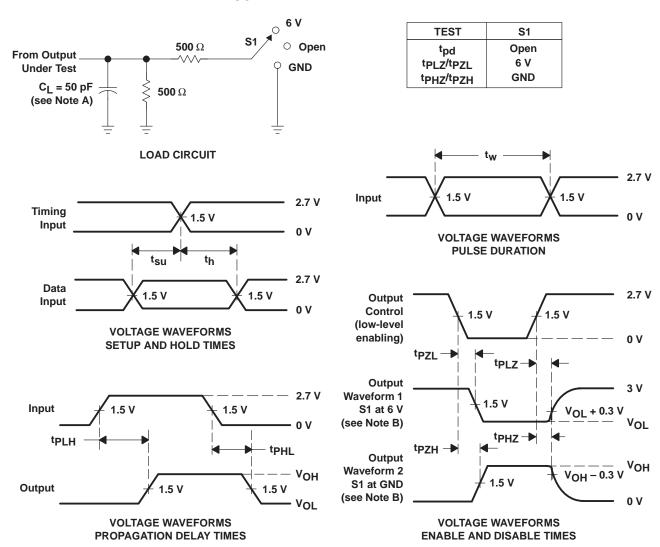
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ ,  $t_f \leq$  2 ns,  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzl and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.7 V AND 3.3 V $\pm$ 0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 2.5 \text{ ns.}$
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms

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